Application Note: AN_SY8003/SY8003A

High Efficiency 5.5V, 3A continuous, 1MHz Synchronous Step Down Regulator

General Description

The SY8003 and SY8003A are high-efficiency, high frequency synchronous step-down DC-DC regulator IC capable of delivering up to 3A output current. The SY8003 and SY8003A operate over a wide input voltage range from 2.7V to 5.5V and integrate main switch and synchronous switch with very low R_DS(ON) to minimize the conduction loss.

Low output voltage ripple and small external inductor and capacitor sizes are achieved with 1MHz switching frequency.

SY8003 and SY8003A integrate reliable short circuit and over-voltage protection.

Ordering Information

SY8003

<table>
<thead>
<tr>
<th>Ordering Number</th>
<th>Package type</th>
<th>Note</th>
</tr>
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<tbody>
<tr>
<td>SY8003DFC</td>
<td>DFN2x2-8</td>
<td></td>
</tr>
<tr>
<td>SY8003ADFC</td>
<td>DFN2x2-8</td>
<td></td>
</tr>
</tbody>
</table>

Features

- Low R_DS(ON) for internal switches (top/bottom): 110mΩ/80mΩ
- 3A continuous load current capability
- 2.7-5.5V input voltage range
- High switching frequency minimizes the external components: 1MHz
- Internal softstart limits the inrush current
- Reliable short circuit protection:
  - SY8003: Latch off protection
  - SY8003A: Hic-cup mode protection
- Reliable over-voltage protection:
  - SY8003: Latch off protection
  - SY8003A: No latch off protection
- 100% dropout operation
- RoHS Compliant and Halogen Free
- Compact package: DFN2X2-8.

Applications

- LCD TV
- Set Top Box
- Net PC
- Mini-Notebook PC
- Access Point Router

Typical Applications

![Figure 1. Schematic diagram](image1)

![Figure 2. Efficiency vs. Load Current](image2)
**SY8003/SY8003A**

**Pinout (top view)**

- **FB 1 8 SGND**
- **PG 2 7 EN**
- **PGND**
- **IN 3 6 LX**
- **PGND 4 5 NC**

### Part Number | Package type | Top Mark
--- | --- | ---
SY8003DFC | DFN2x2-8 | JDxyz
SY8003ADFC | DFN2x2-8 | KWxyz

**Note:** x=year code, y=week code, z= lot number code.

<table>
<thead>
<tr>
<th>Pin Name</th>
<th>Pin Number</th>
<th>Pin Description</th>
</tr>
</thead>
<tbody>
<tr>
<td>EN</td>
<td>7</td>
<td>Enable control. Pull high to turn on. Do not float.</td>
</tr>
<tr>
<td>PGND</td>
<td>4/Exposed Paddle</td>
<td>Power ground pin.</td>
</tr>
<tr>
<td>SGND</td>
<td>8</td>
<td>Signal ground pin.</td>
</tr>
<tr>
<td>LX</td>
<td>6</td>
<td>Inductor pin. Connect this pin to the switching node of inductor.</td>
</tr>
<tr>
<td>IN</td>
<td>3</td>
<td>Power input pin. Decouple this pin to GND pin with at least 10µF ceramic cap.</td>
</tr>
<tr>
<td>PG</td>
<td>2</td>
<td>Power good indicator (Open drain output). Low if the output &lt; 90% of regulation voltage or &gt;120% regulation voltage; High otherwise. Connect a pull-up resistor to the input.</td>
</tr>
<tr>
<td>FB</td>
<td>1</td>
<td>Output Feedback Pin. Connect this pin to the center point of the output resistor divider (as shown in Figure 1) to program the output voltage: Vout=0.6*(1+R1/R2).</td>
</tr>
<tr>
<td>NC</td>
<td>5</td>
<td>No connection.</td>
</tr>
</tbody>
</table>

### Absolute Maximum Ratings (Note 1)

- **Supply Input Voltage**
  
  -0.3V to 6.0V

- **Enable, FB Voltage**
  
  - 0.3V to VIN + 0.6V

- **LX Voltage**
  
  - 0.3V (**1**) to 6V (**2**)

- **Power Dissipation, PD @ TA = 25°C DFN2x2-8**, ---
  
  -1W

### Package Thermal Resistance (Note 2)

- **θ JA**
  
  - 120°C/W

- **θ JC**
  
  - 8.2°C/W

### Junction Temperature Range

- 150°C

### Lead Temperature (Soldering, 10 sec.)

- 260°C

### Storage Temperature Range

- 65°C to 150°C

**Note:**

- **(**1**)** LX Voltage tested down to -5V<10ns
- **(**2**)** LX Voltage tested up to +7V<50ns

### Recommended Operating Conditions (Note 3)

- **Supply Input Voltage**
  
  - 2.7V to 5.5V

- **Junction Temperature Range**
  
  - 40°C to 125°C

- **Ambient Temperature Range**
  
  - -40°C to 85°C
SY8003/SY8003A

Block Diagram

(SY8003)

(SY8003A)
### Electrical Characteristics

(V<sub>IN</sub> = 5V, V<sub>OUT</sub> = 2.5V, L = 2.2µH, C<sub>OUT</sub> = 22µF, T<sub>A</sub> = 25°C, unless otherwise specified)

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Symbol</th>
<th>Test Conditions</th>
<th>Min</th>
<th>Typ</th>
<th>Max</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>Input Voltage Range</td>
<td>V&lt;sub&gt;IN&lt;/sub&gt;</td>
<td></td>
<td>2.7</td>
<td>5.5</td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>Quiescent Current</td>
<td>I&lt;sub&gt;O&lt;/sub&gt;</td>
<td>I&lt;sub&gt;OUT=0&lt;/sub&gt;, V&lt;sub&gt;FB=V&lt;sub&gt;REF&lt;/sub&gt; · 105%&lt;/sub&gt;</td>
<td>55</td>
<td></td>
<td></td>
<td>µA</td>
</tr>
<tr>
<td>Shutdown Current</td>
<td></td>
<td>EN=0</td>
<td>0.1</td>
<td>1</td>
<td></td>
<td>µA</td>
</tr>
<tr>
<td>Feedback Reference Voltage</td>
<td>V&lt;sub&gt;REF&lt;/sub&gt;</td>
<td></td>
<td>0.588</td>
<td>0.6</td>
<td>0.612</td>
<td>V</td>
</tr>
<tr>
<td>FB Input Current</td>
<td>I&lt;sub&gt;FBI&lt;/sub&gt;, V&lt;sub&gt;FBI&lt;/sub&gt;</td>
<td></td>
<td>-50</td>
<td>50</td>
<td></td>
<td>nA</td>
</tr>
<tr>
<td>PFET RON</td>
<td>R&lt;sub&gt;DS(ON)&lt;sub&gt;PF&lt;/sub&gt;</td>
<td></td>
<td>110</td>
<td></td>
<td></td>
<td>mΩ</td>
</tr>
<tr>
<td>NFET RON</td>
<td>R&lt;sub&gt;DS(ON)&lt;sub&gt;N&lt;/sub&gt;</td>
<td></td>
<td>80</td>
<td></td>
<td></td>
<td>mΩ</td>
</tr>
<tr>
<td>PFET Current Limit</td>
<td>I&lt;sub&gt;LM&lt;/sub&gt;</td>
<td></td>
<td>3.5</td>
<td></td>
<td></td>
<td>A</td>
</tr>
<tr>
<td>EN rising threshold</td>
<td>V&lt;sub&gt;ENH&lt;/sub&gt;</td>
<td></td>
<td>1.5</td>
<td></td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>EN falling threshold</td>
<td>V&lt;sub&gt;ENL&lt;/sub&gt;</td>
<td></td>
<td>0.4</td>
<td></td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>EN Leakage current</td>
<td>I&lt;sub&gt;EN&lt;/sub&gt;</td>
<td></td>
<td>-1</td>
<td>1</td>
<td></td>
<td>µA</td>
</tr>
<tr>
<td>Input UVLO threshold</td>
<td>V&lt;sub&gt;UVLO&lt;/sub&gt;</td>
<td></td>
<td>2.5</td>
<td></td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>UVLO hysteresis</td>
<td>V&lt;sub&gt;HYS&lt;/sub&gt;</td>
<td></td>
<td>0.2</td>
<td></td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>Oscillator Frequency</td>
<td>V&lt;sub&gt;OSC&lt;/sub&gt;</td>
<td>I&lt;sub&gt;OUT=500mA&lt;/sub&gt;</td>
<td>0.8</td>
<td>1</td>
<td>1.2</td>
<td>MHz</td>
</tr>
<tr>
<td>PG High Delay Time</td>
<td></td>
<td></td>
<td>0.1</td>
<td>1</td>
<td></td>
<td>µS</td>
</tr>
<tr>
<td>PG Rising Threshold</td>
<td>V&lt;sub&gt;FBHV&lt;/sub&gt;</td>
<td></td>
<td>0.54</td>
<td></td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>PG Under-voltage Threshold</td>
<td>V&lt;sub&gt;FBLV&lt;/sub&gt;</td>
<td></td>
<td>0.54</td>
<td></td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>PG Under-voltage Delay Time</td>
<td></td>
<td></td>
<td>20</td>
<td></td>
<td></td>
<td>µS</td>
</tr>
<tr>
<td>PG Over-voltage Threshold</td>
<td>V&lt;sub&gt;FBLOV&lt;/sub&gt;</td>
<td></td>
<td>0.69</td>
<td>0.72</td>
<td>0.75</td>
<td>V</td>
</tr>
<tr>
<td>Over-voltage Protection Threshold</td>
<td>V&lt;sub&gt;OVP&lt;/sub&gt;</td>
<td></td>
<td>0.69</td>
<td>0.72</td>
<td>0.75</td>
<td>V</td>
</tr>
<tr>
<td>Over-voltage Deglitch Timeout</td>
<td>T&lt;sub&gt;OV&lt;/sub&gt;</td>
<td></td>
<td>10</td>
<td>20</td>
<td>30</td>
<td>µs</td>
</tr>
<tr>
<td>Short Circuit Protection Latch Off Threshold</td>
<td>V&lt;sub&gt;SCP&lt;/sub&gt;</td>
<td>SY8003DFC</td>
<td>0.24</td>
<td></td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>Short Circuit Protection Delay Time</td>
<td>T&lt;sub&gt;DELAY-SC&lt;/sub&gt;</td>
<td></td>
<td>20</td>
<td></td>
<td></td>
<td>µs</td>
</tr>
<tr>
<td>Min ON Time</td>
<td></td>
<td></td>
<td>75</td>
<td></td>
<td></td>
<td>ns</td>
</tr>
<tr>
<td>Max Duty Cycle</td>
<td></td>
<td></td>
<td>100</td>
<td></td>
<td></td>
<td>%</td>
</tr>
<tr>
<td>Soft Start Time</td>
<td>T&lt;sub&gt;SS&lt;/sub&gt;</td>
<td></td>
<td>0.84</td>
<td>1.2</td>
<td>1.56</td>
<td>ms</td>
</tr>
<tr>
<td>Output Discharge Switch Resistance</td>
<td>V&lt;sub&gt;DISH&lt;/sub&gt;</td>
<td></td>
<td>50</td>
<td></td>
<td></td>
<td>Ω</td>
</tr>
<tr>
<td>Thermal Shutdown Temperature</td>
<td>T&lt;sub&gt;SD&lt;/sub&gt;</td>
<td></td>
<td>160</td>
<td></td>
<td></td>
<td>°C</td>
</tr>
</tbody>
</table>

**Note 1:** Stresses beyond the “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

**Note 2:** Test condition: Device mounted on 2” x 2” FR-4 substrate PCB, 2oz copper, with minimum recommended pad on top layer and thermal vias to bottom layer ground plane.

**Note 3:** The device is not guaranteed to function outside its operating conditions.
Typical Performance Characteristics

Efficiency vs. Load Current

Efficiency (%) vs. Load Current (A)

- 5V_in, 1.2V_out
- 4.2V_in, 1.2V_out

Output Ripple

(V_in=5.0V, V_out=1.8V, I_out=3mA)

Efficiency ( % ) vs. Load Current (A)

- 5V_in, 1.8V_out
- 4.2V_in, 1.8V_out

Startup from Enable

(V_in=5.0V, V_out=1.8V, I_out=3mA)

Shutdown from Enable

(V_in=5.0V, V_out=1.8V, I_out=3mA)

Time (400ms/div)

Time (1ms/div)

Time (20us/div)
**Operation Principle**

SY8003 is a synchronous buck regulator IC that integrates the PWM control, top and bottom switches on the same die to minimize the switching transition loss and conduction loss. With ultra low \( R_{DS(ON)} \) power switches and proprietary PWM control, this regulator IC can achieve the highest efficiency and the highest switch frequency simultaneously to minimize the external inductor and capacitor size, and thus achieving the minimum solution footprint.

**Short Circuit Protection**

(SY8003) After the soft start is over, if the output voltage falls below 40\% of the regulation level, IC will turn off both power switches, entering short circuit protection. It will remain in this state until the IN or EN voltage is recycled.

(SY8003A) The frequency is folded back to about 30\% of the nominal frequency and the current limit is folded back to 3.0A to prevent the inductor current from runaway and to reduce the power dissipation of the IC under short circuit conditions.

**Over-voltage Protection (SY8003 Only)**

If the output voltage exceeds 120\% of the regulation level for more than 20\mu s, IC will turn off both power switches and turn on the discharge switch, entering over-voltage protection. It will remain in this state until the IN or EN voltage is recycled.

**Feedback resistor dividers R1 and R2:**

Choose \( R_1 \) and \( R_2 \) to program the proper output voltage. To minimize the power consumption under light loads, it is desirable to choose large resistance values for both \( R_1 \) and \( R_2 \). A value of between 10k and 1M is highly recommended for both resistors. If \( \Delta V_{OUT} \) is 1.8V, \( R_1 = 100k \) is chosen, then \( R_2 \) can be calculated to be 50k.

\[
\begin{align*}
R_2 &= \frac{0.6V}{V_{OUT} - 0.6V} \\
V_{OUT} &= \frac{1}{R_1} (\frac{R_2}{V_{OUT} - 0.6V})
\end{align*}
\]

**Input capacitor CIN:**

This ripple current through input capacitor is calculated as:

\[
I_{CIN\_RMS} = I_{OUT} \times \sqrt{D(1-D)}
\]

This formula has a maximum at \( V_{IN} = 2V_{OUT} \) condition, where \( I_{CIN\_RMS} = I_{OUT}/2 \). This simple worst-case condition is commonly used for DC/DC design.

With the maximum load current at 3.0A. A typical X5R or better grade ceramic capacitor with 6.3V rating and more than 1 pcs 22\mu F capacitor can handle this ripple current well. To minimize the potential noise problem, ceramic capacitor should really be placed close to the IN and GND pins. Care should be taken to minimize the loop area formed by CIN, and IN/GND pins.

**Output capacitor COUT:**

The output capacitor is selected to handle the output ripple noise requirements. Both steady state ripple and transient requirements must be taken into consideration when selecting this capacitor. For the best performance, it is recommended to use X5R or better grade ceramic capacitor with 6.3V rating and greater than 22\mu F capacitance.

**Output inductor L:**

There are several considerations in choosing this inductor.

1) Choose the inductance to provide the desired ripple current. It is suggested to choose the ripple current to be about 40\% of the maximum output current. The inductance is calculated as:

\[
L = \frac{V_{OUT}}{F_{SW} \times I_{OUT\_MAX}} \times \frac{1}{\frac{V_{OUT}}{V_{IN\_MAX}}}
\]

where \( F_{SW} \) is the switching frequency and \( I_{OUT\_MAX} \) is the maximum load current.

The SY8003 regulator IC is quite tolerant of different ripple current amplitude. Consequently, the final choice of inductance can be slightly off the calculation value without significantly impacting the performance.

2) The saturation current rating of the inductor must be selected to be greater than the peak inductor current under full load conditions:

\[
I_{SAT\_MIN} > I_{OUT\_MAX} + \frac{V_{OUT}}{2 \times F_{SW} \times L} \times (1 - \frac{V_{OUT}}{V_{IN\_MAX}})
\]

3) The DCR of the inductor and the core loss at the switching frequency must be low enough to achieve the desired efficiency requirement. It is
desirable to choose an inductor with DCR<50mΩ to achieve a good overall efficiency.

Enable Operation
Pulling the EN pin low (<0.4V) will shut down the device. During shut down mode, the SY8003 shutdown current drops to lower than 0.1uA. Driving the EN pin high (>1.5V) will turn on the IC again.

Load Transient Considerations:
The SY8003 regulator IC integrates the compensation components to achieve good stability and fast transient responses. In some applications, adding a 22pF ceramic cap in parallel with R1 may further speed up the load transient responses and is thus recommended for applications with large load transient step requirements.

Layout Design:
The layout design of SY8003 regulator is relatively simple. For the best efficiency and minimum noise problems, we should place the following components close to the IC: CIN, L, R1 and R2.

1) It is desirable to maximize the PCB copper area connecting to GND pin to achieve the best thermal and noise performance. If the board space allowed, a ground plane is highly desirable.

2) CIN must be close to Pins IN and GND. The loop area formed by CIN and GND must be minimized.

3) The PCB copper area associated with LX pin must be minimized to avoid the potential noise problem.

4) The components R1, R2, and the trace connecting to the FB pin must NOT be adjacent to the LX net on the PCB layout to avoid the noise problem.

4) If the system chip interfacing with the EN pin has a high impedance state at shutdown mode and the IN pin is connected directly to a power source such as a LiIon battery, it is desirable to add a pull down 1MΩ resistor between the EN a d GND pins to prevent the noise from falsely turning on the regulator at shutdown mode.
DFN2x2-8 Package Outline

Notes:  
All dimension in MM  
All dimension don’t not include mold flash & metal burr
1. DFN2x2

2. Carrier Tape & Reel specification for packages

3. Others: NA